

## Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.58 \text{ V}$  at  $I_F = 5 \text{ A}$ 





#### V20M120M



| PRIMARY CHARACTERISTICS   |                |  |  |  |
|---|----------------|--|--|--|
| I <sub>F(AV)</sub>  | 2 x 10 A       |  |  |  |
| V <sub>RRM</sub>  | 120 V          |  |  |  |
| I <sub>FSM</sub>  | 110 A          |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 10 A (T <sub>A</sub> = 125 °C) | 0.68 V         |  |  |  |
| T <sub>J</sub> max.   | 175 °C         |  |  |  |
| Package   | TO-220AB       |  |  |  |
| Diode variations  | Common cathode |  |  |  |

#### **FEATURES**

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

• High efficiency operation

RoHS

Solder dip 275 °C max. 10 s, per JESD 22-B106
Material categorization: for definitions of

 Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)                    |            |                                   |             |      |  |
|--|------------|-----------------------------------|-------------|------|--|
| PARAMETER  |            | SYMBOL                            | V20M120M    | UNIT |  |
| Maximum repetitive peak reverse voltage  |            | $V_{RRM}$                         | 120         | V    |  |
| Maximum average forward rectified current (fig. 1)                                 | per device | I <sub>F(AV)</sub>                | 20          | ^    |  |
|  | per diode  |                                   | 10          | A    |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load |            | I <sub>FSM</sub>                  | 110         | А    |  |
| Voltage rate of change (rated V <sub>R</sub> )                                     |            | dV/dt                             | 10 000      | V/µs |  |
| Operating junction and storage temperature range                                   |            | T <sub>J</sub> , T <sub>STG</sub> | -55 to +175 | °C   |  |



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                        |                         |                               |      |      |      |  |  |
|---|------------------------|-------------------------|-------------------------------|------|------|------|--|--|
| PARAMETER   | TEST CONDITIONS        |                         | SYMBOL                        | TYP. | MAX. | UNIT |  |  |
| Instantaneous forward voltage per diode   | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.70 | -    | V    |  |  |
|   | I <sub>F</sub> = 10 A  |                         |                               | 0.93 | 1.01 |      |  |  |
|   | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 125 °C |                               | 0.58 | -    |      |  |  |
|   | I <sub>F</sub> = 10 A  |                         |                               | 0.68 | 0.76 |      |  |  |
| Reverse current per diode   | V <sub>R</sub> = 100 V | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | 2.0  | -    | μA   |  |  |
|   |                        | T <sub>A</sub> = 125 °C |                               | 1.5  | -    | mA   |  |  |
|   | V <sub>R</sub> = 120 V | T <sub>A</sub> = 25 °C  |                               | -    | 500  | μΑ   |  |  |
|   |                        | T <sub>A</sub> = 125 °C |                               | 2.0  | 12   | mA   |  |  |

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |            |                          |          |      |  |
|---|------------|--------------------------|----------|------|--|
| PARAMETER   |            | SYMBOL                   | V20M120M | UNIT |  |
| Typical thermal resistance  | per diode  | R <sub>θJC</sub>         | 2.8      |      |  |
|   | per device |                          | 1.4      | °C/W |  |
|   | per device | R <sub>0</sub> JA (1)(2) | 40       |      |  |

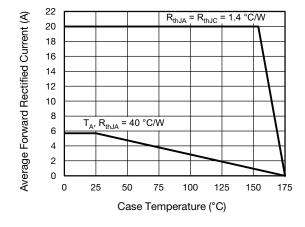
#### **Notes**

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient  $dP_D/dT_J < 1/R_{\theta,JA}$ 

(2) Free air, without heatsink

| ORDERING INFORMATION (Example) |                |                 |              |               |               |  |  |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE                        | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |
| TO-220AB                       | V20M120M-E3/4W | 1.88            | 4W           | 50/tube       | Tube          |  |  |

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





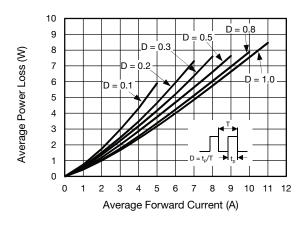


Fig. 2 - Forward Power Loss Characteristics Per Diode



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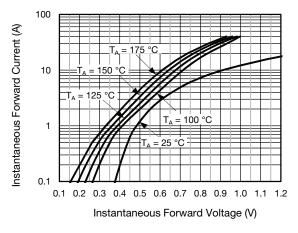


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

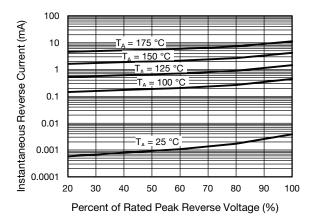


Fig. 4 - Typical Reverse Characteristics Per Diode

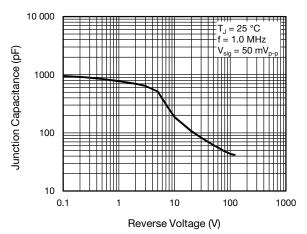


Fig. 5 - Typical Junction Capacitance Per Diode

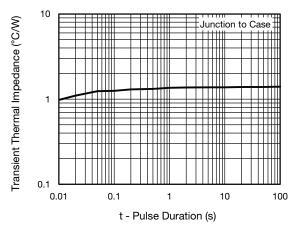
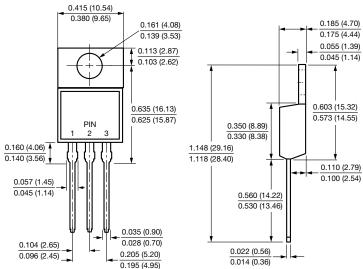


Fig. 6 - Typical Transient Thermal Impedance Per Device

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-220AB





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